Superconductivity of Ca₂InN with a layered structure embedding anionic indium chain array

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Abstract

We report the emergence of superconductivity in Ca₂InN consisting of a 2-dimensional (2D) array of zigzag indium chains embedded between Ca₂N layers. A sudden drop of resistivity and a specific-heat (C_p) jump attributed to the superconducting transition were observed at 0.6 K. The Sommerfeld coefficient $\gamma = 4.24$ mJ/mol K² and Debye temperature $\Theta_D = 322$ K were determined from the C_p of the normal conducting state and the superconducting volume fraction was estimated to be ~80% from the C_p jump, assuming a BCS-type weak coupling. Density functional theory calculations demonstrated that the electronic bands near the Fermi level (E_F) are mainly derived from In 5p orbitals with π and σ bonding states and the Fermi surface is composed of cylindrical parts, corresponding to the quasi-2D electronic state of the In chain array. By integrating the projected density of states of In-p component up to E_F , a valence electron population of ~1.6 electrons/In was calculated, indicating that the partially anionic state of In. The In 3d binding energies observed in Ca₂InN by x-ray photoemission spectroscopy were negatively shifted from that in In metal. The superconductivity of Ca₂InN is associated with the *p*-*p* bonding states of the anionic In layer.

1. Introduction

Superconductivity of magnesium diboride (MgB₂) shows the highest critical temperature ($T_c =$ 39 K) among the intermetallic compounds [1]. Therefore, related intermetallic compounds have attracted attention as potential new superconductors. MgB₂ is composed of a graphite-structured hexagonal boron (B) layer and a layer of magnesium (Mg) atoms. Since electrons are transferred from Mg to B, the formal charge of B is -1 with electronic configuration of $2s^22p^2$. The metallic state is derived via electron transfer from the σ bands made up of B $p_{x,y}$ orbitals to the π bands containing B p_z orbitals [2-4]. We can find similar anionic *p*-block metal layers in other intermetallic superconductors. For example, the anionic Bi ($6s^2 6p^4$) square net produced by Bi 6p-Bi $6p \sigma/\pi$ bonding is responsible for the superconductivity of RNi_xBi_2 (R = La, Ce, Nd and Y) compounds [5]. Moreover, the superconductive Zintl phases such as $AESn_x$ (AE = Sr, Ba) have intermetallic anionic Sn-layered structures containing π bonding systems [6, 7].

In this paper, we report the investigation of superconductivity (critical temperature $T_c = 0.6$ K) in Ca₂InN [8] containing a 2-dimensional (2D) chain array of anionic In $(5s^25p^{1+\delta})$. Density functional theory (DFT) calculations and X-ray photoemission spectroscopy (XPS) measurements indicate that the superconductivity arises from the anionic state of the In layer [-(In^{0.6-})-] which is formed by In 5*p* orbitals with π and σ bonding states.

2. Experimental details

The polycrystalline Ca_2InN was synthesized by the reaction of Ca_2N and In metal. All handling was performed in an argon-filled glove box with oxygen and moisture levels below 1 ppm. The starting Ca_2N powder was synthesized by solid-state reaction between Ca_3N_2 powder and Cashots as described in reference [8]. A mixture of Ca_2N and In was pressed into a pellet and the pellet was wrapped with molybdenum foil and sealed into a silica glass ampoule filled with argon gas at atmospheric pressure. The ampoule was then heated at 873 K for 50 h. For homogeneity, the obtained samples were ground and heated again under the same conditions. Sintered Ca₂InN polycrystalline samples were tinted dark brown, and decomposed when exposed to air.

The crystalline phase and structure were identified by powder x-ray diffraction (PXRD) using Mo K α radiation at 300 K. The sample was ground into a powder and placed in a glass capillary (ϕ 0.5 mm) to reduce effects of preferential orientation of crystallites. Rietveld refinement of the PXRD patterns was performed using TOPAS software [9].

The temperature dependence of dc electrical resistivity (ρ) and heat-capacity (C_p) were measured in the temperature range of 0.4-300 K both without and with a static magnetic field of up to 2 kOe, using a physical property measurement system (PPMS) with He³ refrigeration system. Electronic band structure, density of state (DOS) and Fermi surface calculations were performed using the generalized gradient approximation (GGA), Perdew-Burke-Ernzerhof (PBE) functional, and the projected augmented plane-wave (PAW) method [10, 11] implemented in the Vienna *ab* initio simulation program (VASP) code [12]. A primitive unit cell containing two chemical formula units was used, and the plane-wave basis-set cutoff was set to 900 eV. For Brillouin-zone integrations to calculate the total energy and DOS, $8 \times 8 \times 20$ Monkhorst-pack *k* point grids were used [13]. To obtain the projected DOS, the charge density was decomposed over the atom-centered spherical harmonics; Wigner-Seitz radii of 0.20(1) nm for In, 0.16(8) nm for Ca and 0.08(3) nm for N were used for the PDOS calculation. The Fermi surface was visualized using Xcrysden software [14]. The electron localization function (ELF) was calculated to clarify the chemical bonding state by identifying whether the electrons were localized or delocalized.

The oxidation state of Ca₂InN was confirmed by XPS and ultraviolet photoelectron spectra (UPS) measurements using a hemispherical analyzer [x-ray (Mg K_{α} line: hv = 1253.6 eV) source and Non-monochromatic UV photons (He I line: hv = 21.2 eV) source]. To prepare a

clean surface, the sample was cleaved under high vacuum. All XPS spectra were measured at room temperature and displayed as a function of the electron binding energy with respect to the Fermi level. The core level spectra were subsequently deconvoluted using a least squares Gaussian fit method.

3. Results and discussion

All peaks in the PXRD pattern could be indexed to an orthorhombic structure (space group: Cmcm) with lattice parameters: a = 0.352(9) nm, b = 2.020(7) nm and c = 0.496(9) nm (See figure S1 and table S1 of supplementary data). These values agreed well with those in the literature [15]. Figure 1 shows the crystal structure of Ca₂InN, made up of alternate Ca₂N layer and one dimensional zigzag chains of In layers along the *b*-axis [15]. The Ca₂N layer consists of edge shared Ca₆N octahedra and contains two non-equivalent Ca sites respectively shared by two and four octahedra. Each Ca₂N layer has separation of 0.468 nm, which is 20 % larger than that found in Ca₂N (0.386 nm) [8]. The In layer embedded between the Ca₂N layers forms an array of zigzag chains parallel to the *c*-axis. The In-In-In bond angle is 115.12° and In-In bond length is 0.294 nm, which is 10 % shorter than the shortest separation (0.325 nm) in metallic In. The inter-chain In-In distance (along the *a*-axis) is 0.353 nm, which is 20 % larger than the intra-chain In-In bond length.

Figure 2(a) shows the temperature dependence of electrical resistivity. Metallic behavior, with resistivity decreasing with decreasing temperature, was seen; the resistivity value at room temperature was 27 m Ω ·cm. A sudden drop to zero resistivity occurred at 0.7 K; this drop was not seen when a magnetic field of H = 2 kOe [inset of figure 2(a)] was applied. Figure 2(b) shows specific heat data (plotted as C_p/T vs. T^2), below 1.2 K, collected at H = 0 and 2 kOe. A jump was observed from T = 0.7 K without magnetic field, but was completely suppressed when H = 2 kOe. These results clearly indicate that bulk superconductivity appears from 0.7 K. The

specific heat above T = 0.7 K when H = 0 Oe, i.e., in the non-superconducting state, can be fitted to the formula:

$$C_p / T = (C_e + C_l) / T = \gamma + \beta T^2$$
(1)

where C_e and C_1 denote electronic and lattice contributions to the total specific heat [16]. The obtained γ and β values were 4.24 mJ/mol K² and 1.39 mJ/mol K⁴, respectively. The inset of figure 2(b) shows the electronic specific heat data (plotted as C_e/T vs. *T*) for Ca₂InN. $T_c^{\text{mid.}} =$ 0.6 K was defined as the midpoint of the specific heat jump, and the height of the heat capacity jump ($\Delta C_p^{\text{obs.}}$) was 2.85 mJ/mol K. The Debye temperature (Θ_D) is estimated as 322 K by using:

$$\Theta_D = (12\pi^4 nR / 5\beta)^{1/3} \tag{2}$$

where *n* is the number of atoms per formula unit of Ca₂InN and *R* is the gas constant. To evaluate the electron-phonon coupling constant (λ_{el-ph}), we use McMillan's expression[17]:

$$T_{c}^{mid.} = (\Theta_{D} / 1.45) \exp\{\left[-1.04(1 + \lambda_{el-ph})\right] / \left[\lambda_{el-ph} - \mu^{*}(1 + 0.62\lambda_{el-ph})\right]\}$$
(3)

where the μ^* is the retarded Coulomb repulsion parameter and usually amounts to 0.1- 0.2. Substituting 0.1 and 0.2 for μ^* , we get $\lambda_{el-ph} = 0.36$ for 0.1 and $\lambda_{el-ph} = 0.53$ for 0.2, and find that Ca₂InN is classified as a weak-coupling BCS-type superconductor [17].

According to BCS theory for weak coupling, the superconducting volume fraction was evaluated to be 78% from

$$\Delta C_p^{obs.}(T_c) / \Delta C_p^{BCS}(T_c)$$
(4)

where the theoretical heat jump at T_c (ΔC_p^{BCS}) is predicted to 3.64 mJ/mol K from BCS theory.

$$\Delta C_p^{BCS} \left(T_C \right) / \gamma T_c = 1.43 \tag{5}$$

Figure 3(a) shows the calculated electronic band structure, with total and projected DOS

(PDOS) per formula unit (f. u.), for Ca₂InN. Here, we noted that the narrow entangled bands located from -3 to -1 eV with Ca *d* character did not appear in the band structure calculated by extended Hückel method in the past report [15]. This difference is due to a flaw of the calculation method ignoring the contribution of Ca 3*d* orbitals. The four bands which cross the $E_{\rm F}$ and form a DOS peak around $E_{\rm F}$ (-0.9 eV < E < 2.0 eV) are mainly made up of In 5*p* bands with small contributions from the atomic orbitals of Ca and N, as shown in the PDOS. The energy levels of N and Ca are far from the $E_{\rm F}$, and In 5*p* bands are inserted between the N 2*p* and Ca 3*d* bands. By integrating the PDOS on the In 5*p* orbital up to $E = E_{\rm F}$, we find that the valence of In in Ca₂InN is $\ln^{0.6-}$, i.e., the electronic configuration of In may be expressed as [Kr]4*d*¹⁰5*s*²5*p*^{1.6}. This calculated result indicates that the anionic indium layer includes a *p*-band, which is stabilized by the strong electron donating ability of the [Ca₂N]⁺ cationic framework. The cationic Ca₂N layer is also found in dicalcium nitride Ca₂N regarded as 2D electride [Ca₂N]⁺*e*⁻, while the connecting pattern of Ca₆N octahedron is a little different [8, 18]. The ionicity of Ca₂N layer is so strong that electrons are pushed out to empty inter-layer space.

Figure 3(b) shows the Fermi surface of Ca₂InN. The two kinds of cylindrical sheets along Γ -Y, which are parallel to the direction of the alternate stacking of Ca₂N and In layers (*b*-direction in conventional cell), are perpendicular to the In-chain array direction (*a*- and *c*-direction in conventional cell). Additionally, one kind of the cylindrical sheets around the R and S points consist of flat planes along the Γ -Z direction, which are perpendicular to the In-chain direction (*c*-axis; figure 1). This result suggests that the embedded In zigzag chain (quasi-one-dimensional) array in Ca₂InN has an electronic structure with 2D character, with some flat areas in the Fermi surface because of the binding state within the In-chain array. The 3D character, which occurs along the Γ -Z direction, comes from the orbital interactions between In 5*p* and Ca 3*d*, N 2*p*. The electronic structure can also be seen in the calculated ELF in figure 3(c). The large ELF values around Ca and N atoms reflect that the chemical bond between Ca

and N atoms is ionic. In contrast, the small ELF values spread around the In-chain direction and inter-chain direction indicate that the electrons are 2D delocalized along the In-chain array, and are independent from the Ca₂N layer.

Figure 3(d) shows orbital angular momentum projected DOS on In site. The In $5p_x$, $5p_y$ and $5p_z$ orbitals contribute to the four entangled bands near E_F . These bands are dispersed along Γ -S, R-Z (along the *a*-direction) and S-R (along the *c*-direction). These results imply that the electronic properties of Ca₂InN are attributable to the $p\sigma$ and $p\pi$ bonding complex in the a-, and *c*-directions (In-chain array plane) of the In 5p orbital, which is occupied by electrons supplied from the $[Ca_2N]^+$ cationic layer. The In-In distance along In-chain shorter than that in In metal is consistent with the participation of $p\sigma$ and $p\pi$ bonding nature to the intra In-In bonding. In other words, electrons mainly occupy the bonding molecular orbitals of $-(In)_n$ polymer and the bond length is shortened as a result. This is in contrast to the bonding state of indium metal in which each In atom is loosely bound by metallic bonding mediated by 3-dimensinally delocalized 5s and 5p electrons. Therefore, we identify that the superconductivity in Ca₂InN originates from the In 5p state of the In-chain array. The strength of intra-chain bonding has been confirmed by means of crystal orbital overlap populations calculation in the reference [15]. Because the anionic In $(5s^2 p^{1.6})$ state induces a complex σ and π bonding state, and the In structure has a low dimensionality electronic structure because of the In zigzag chain array, the In 5p state in Ca₂InN has a more narrow band dispersion than that found in either the 3D cationic In 5s or 3D anionic In 5p states. Actually, the 2D anionic In (In^{0.6-}) state in Ca₂InN has a narrower band width (~4.1 eV) than that of the 3D anionic In (In_5^{7-}) band in Sr₃In₅ zintl phase (~5 eV) [19].

Finally, the charge state of In was examined by XPS. Figure 4 shows the In 3*d* XPS spectrum of the sample. Two peaks are identified as In $3d_{3/2}$ at 451.0 eV and In $3d_{5/2}$ at 443.5 eV. A shoulder at 444.5 eV was assigned to In³⁺, originating from the surface state [20, 21]. These observed In 3*d* binding energies show a significant lower energy shift compared to those of

indium oxide (444.5 \pm 0.1 eV; +3 charge state) and pure indium (443.9 \pm 0.1 eV; neutral state) [22-24]. This finding indicates that the charged state of In in Ca₂InN is negative, which is compatible with DFT calculations (In^{0.6-}), and demonstrates that Ca₂N electride acts as a strong electron donor.

Since the Ca₂InN and In metal are weak coupling BCS type superconductor [25-26], the T_c can be estimated by the equation:

$$T_c = 1.13 \, \Theta_D \exp\left(-1 \,/ \, VN(E_F)\right) \tag{6}$$

where Θ_D , V and $N(E_F)$ are Debye temperature, the paring potential of electron-electron interaction and the density of state at the E_F , respectively. As evidence from equation (6), $N(E_F)$ and V are the dominant factors for T_c determination, whereas Θ_D plays a minor role. By putting experimental values of T_c and Θ_D , and the calculated value of $N(E_F)$ by DFT to equation (6), the value of V was estimated. Table 1 summarizes the parameters associated with superconductivity of Ca₂InN and In metal. While V is close in these systems, Θ_D of Ca₂InN is 3 times higher than that of In metal, corresponding to strength of In-In bond. However, $N(E_F)$ of Ca₂InN is 0.5 times smaller than that of In metal. This small $N(E_F)$ is the main reason for lower T_c of Ca₂InN, though 2D structure is generally considered to be favorable to enhance $N(E_F)$. This result implies that Ca₂N block layer is rather thick to get the high volume density of In chain.

4. Summary

We reported a BCS-type superconductivity with $T_c = 0.6$ K in Ca₂InN composed of 2D anionic In-chain array embedded between Ca₂N layers. By assuming a BCS-type weak coupling, the superconducting volume fraction was estimated to be ~80%. From DFT calculations, we conclude that the superconductivity arises due to the anionic state of the In layer [-(In^{0.6-})-] which is formed by In 5*p* orbitals with π and σ bonding states. The anionic state of In was experimentally confirmed by the XPS chemical shift. The strong ionicity of Ca₂N layer could be applied for stabilizing various anionic metal layer forming $p\sigma$ and $p\pi$ bonding system similar to MgB₂ and related compounds. If an appropriate *p*-block elemental is chosen and embedded instead of In, we expect that the resulting compound would also exhibits superconductivity.

Acknowledgments

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Figure Captions

Figure 1 Crystal structure of Ca_2InN . Green, light blue and gold spheres represent Ca, N and In atoms, respectively. Solid and dashed dark brown lines represent the conventional and primitive unit cell. Bond angle and distances were obtained from Rietvelt analysis.

Figure 2 Physical properties of Ca₂InN. (a) Temperature dependence of electrical resistivity (ρ). Inset shows ρ - *T* curves under magnetic fields of 0 (open circle) and 0.2 kOe (open square). (b) Low temperature heat capacity under magnetic fields of 0 (open circle) and 0.2 kOe (open square). Inset is the temperature dependence of the electronic specific heat data divided by temperature, C_e / T . The solid gray curve is the theoretical curve according to BCS theory [16].

Figure 3 Calculated electronic structure of Ca₂InN. (a) Band structure and total density of states (DOS) and atomic projected DOS (PDOS). For the band structure, the green, blue and red circle size lines on the left-hand side of the figure denote the widths of the atomic distributions of Ca, In and N. In the DOS, the black line denotes the total DOS of Ca₂InN, and the green, blue, orange and red lines denote the Ca *d*, In *p*, In *s* and N *p*, DOS, respectively. (b) Fermi surface of the first Brillouin zone. Some of the high symmetry points are shown. (c) Electron-localization function (ELF) of the total electron density on the (2 0 0), (0 0 3) plane parallel to the *b*-axis. Solid dark brown lines represent the primitive unit cell. (d) PDOS of In 5*p*. The black, pink and blue line thicknesses indicate the widths of the distributions of energy of the p_x , p_y , and p_z components of the In 5*p*, respectively. Beside the PDOS, a schematic of the bonding state on the zigzag In chain is shown. The gold spheres represent the In atoms.

Figure 4 X-ray photoemission spectrum of Ca_2InN (In 3*d* region). Solid lines (blue and red) are the results of Gaussian deconvolution of the peak. The inset shows the He I (hv = 21.2 eV) ultraviolet photoelectron spectrum (UPS) valence band of Ca_2InN .

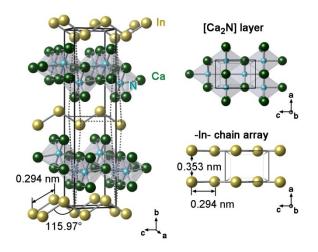


Figure 1

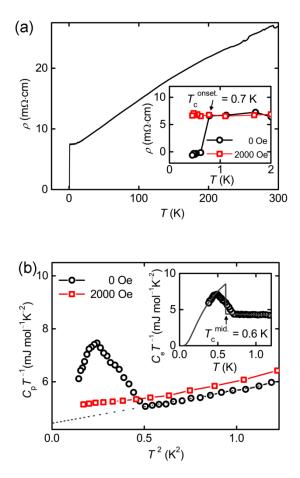


Figure 2

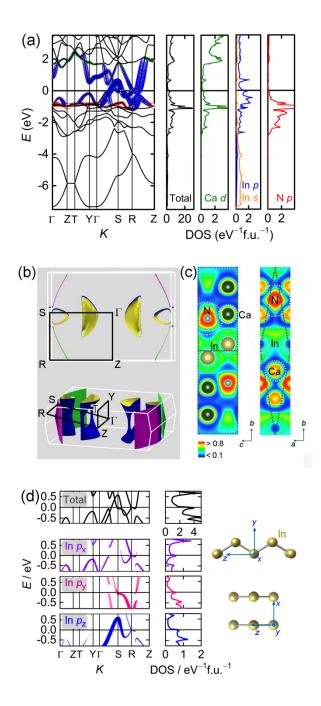


Figure 3

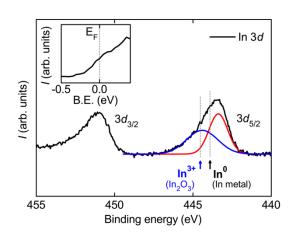


Figure 4

Ca ₂ InN	Parameter	In metal
0.6	$T_{\rm c}$ (K)	3.41
322	$\Theta_{\mathrm{D}}\left(\mathrm{K} ight)$	108
2.29	$N(E_F) (eV^{-1} \cdot nm^{-3})$	4.59
0.068	V	0.058

Table 1. Comparison of the superconducting parameters between Ca_2InN and In metal.